

4.5Ω、300MHz 带宽、双通道单刀双掷（SPDT）模拟开关

UM4717 CSP10 1.90×1.40
UM4717Q QFN10 1.80×1.40

描述

UM4717/UM4717Q是一款低电压、低导通电阻、双通道单刀双掷（SPDT）模拟开关，采用 +1.8V 至 +5.5V 单电源供电。该器件专为USB 1.1/2.0接口和音频开关应用而设计。

UM4717 具有2路最大导通电阻为4.5Ω的单刀双掷（SPDT）开关，通道间平坦度为1.2Ω，匹配度为0.3Ω；UM4717Q 具有2路最大导通电阻为6Ω的单刀双掷（SPDT）开关，通道间平坦度为1.8Ω，匹配度为0.6Ω。这些器件在+2.7V电压下为先断后连开关（1ns），其 $t_{ON} < 80ns$ ， $t_{OFF} < 40ns$ 。逻辑输入与 +1.8V逻辑兼容，兼容 +2.7V 至 +3.6V 电源。

UM4717采用CSP封装，尺寸仅为1.90mm×1.40mm，具有4×3球形阵列，球形间距为0.50mm。UM4717Q采用1.80mm×1.40mm QFN10封装，大大减少了所需的PCB面积。

应用

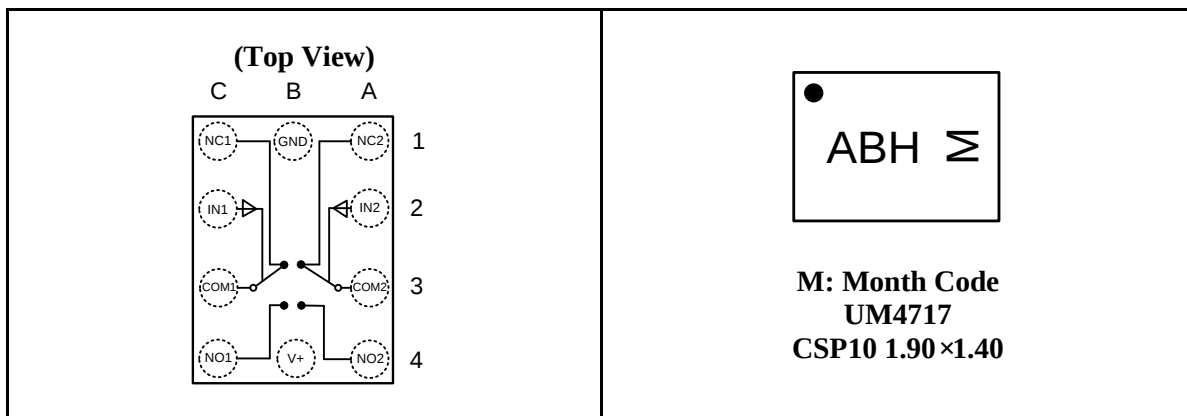
- USB 1.1/2.0 信号切换电路
- 电池供电设备
- 音频/视频信号路由
- 耳机切换
- 低压数据采集系统
- 采样和保持电路
- 手机
- 掌上电脑

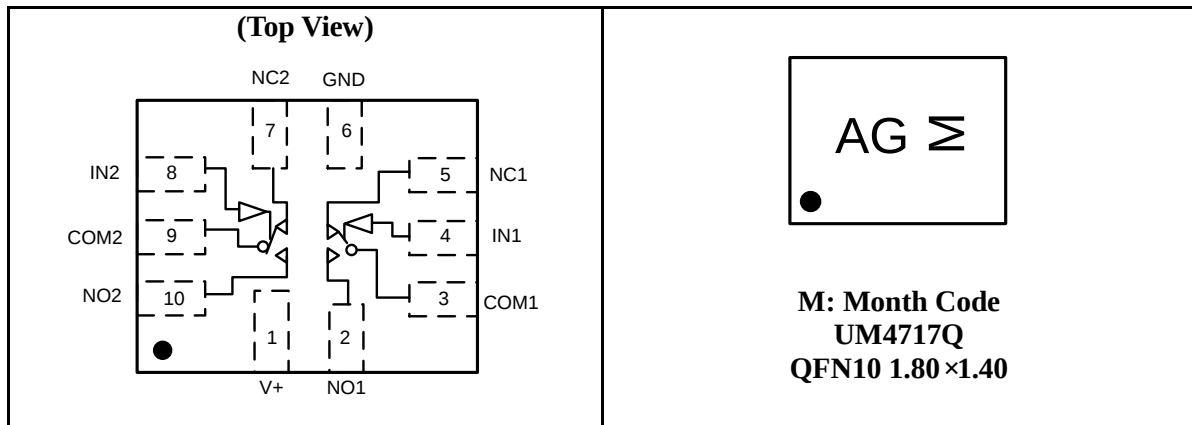
特性

- 2ns (最大) 差分偏移
- -3dB 带宽: 300MHz
- 低至 15pF 的通道电容
- +1.8V 至 +5.5V 单电源运行
- +3V 电源时典型 R_{ON} (最大值): 4.5Ω (UM4717), 6Ω (UM4717Q)
- 轨对轨信号处理
- 高隔离度: -50dB (10MHz)
- 低串扰: -70dB (10MHz)
- 低失真: 0.03%
- 兼容+1.8V CMOS 逻辑
- +25℃ 时的漏电流< 0.5nA

引脚配置

顶部视图





Ball Mapping for UM4717

C	B	A	
NC1	GND	NC2	1
IN1		IN2	2
COM1		COM2	3
NO1	V+	NO2	4

Transparent Top View

Pin Description

Pin		Name	Function
UM4717	UM4717Q		
A1	7	NC2	Analog Switch 2-Normally Closed Terminal
A2	8	IN2	Analog Switch 2-Digital Control Input
A3	9	COM2	Analog Switch 2-Common Terminal
A4	10	NO2	Analog Switch 2-Normally Open Terminal
B1	6	GND	Ground Connection
B4	1	V+	Positive Supply Voltage
C1	5	NC1	Analog Switch 1-Normally Closed Terminal
C2	4	IN1	Analog Switch 1-Digital Control Input
C3	3	COM1	Analog Switch 1-Common Terminal
C4	2	NO1	Analog Switch 1-Normally Open Terminal

Ordering Information

Part Number	Packaging Type	Marking Code	Shipping Qty
UM4717	CSP10 1.90×1.40	ABH	3000pcs/7 Inch Tape & Reel
UM4717Q	QFN10 1.80×1.40	AG	3000pcs/7 Inch Tape & Reel

Function Table

IN_	NO_	NC_
0	OFF	ON
1	ON	OFF

Absolute Maximum Ratings

Symbol	Parameter		Limit	Unit
V ₊	Supply Voltage		-0.3 to +6.0	V
V _S	DC Switch Voltage (Note 1)		-0.3 to (V ₊ +0.3)	
IN_	DC IN Voltage		-0.3 to +6.0	
I _O	Continuous Current (COM_, NO_, NC_)		±100	mA
I _P	Peak Current (Pulsed at 1ms, 10% Duty Cycle)		±200	
T _O	Operating Temperature Range		-40 to +85	℃
T _J	Junction Temperature		+150	
T _{STG}	Storage Temperature Range		-65 to +150	
T _L	Junction Lead Temperature (Soldering, 10 Seconds)		+300	
T _{Bump}	Bump Temperature (Soldering)	Infrared (15s)	+220	
		Vapor Phase (60s)	+215	
P _D	Continuous Power Dissipation @ +70 ℃		909	mW
ESD	ESD Method 3015.7		>2000	V

Note 1: Signals on COM_, NO_, or NC_ exceeding V₊ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Electrical Characteristics (Single +3V Supply)

($V_+ = +2.7V$ to $+3.6V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +3.0V$, $T_A = +25^\circ C$) (Notes 2, 3)

Symbol	Parameter	Test Conditions		Temp	Limits (−40 °C to 85 °C)			Unit
					Min	Typ	Max	
DC Electrical Characteristics								
V _{COM_} V _{NO_} V _{NC_}	Analog Signal Range			Full	0		V ₊	V
V ₊	Power Supply Range			Full	1.8		5.5	V
I ₊	Supply Current	V ₊ =+5.5V, V _{IN} =0V or V ₊		Full			1	μA
I _{COM_} (ON)	COM_On Leakage Current (Note 4)	V ₊ =+3.6V, V _{COM_} =0.3V, 3.3V; V _{NO_} or V _{NC_} =0.3V, 3.3V, or Floating		Room Full	-1 -2	+0.01	+1 +2	nA
I _{OFF}	OFF State Leakage Current (Note 4)	V ₊ =+3.6V, V _{COM_} =0.3V, 3.3V; V _{NO_} or V _{NC_} =3.3V, 0.3V		Room Full	-0.5 -1	+0.01	+0.5 +1	nA
V _{IH}	Input High Voltage			Full	1.6			V
V _{IL}	Input Low Voltage			Full			0.5	V
I _{IN}	Input Leakage Current	V ₊ =+3.6V, V _{IN_} =0 or 5.5V		Full	-100		+100	nA
R _{ON}	On-Resistance (Note 4)	V ₊ =+2.7V, I _{COM_} =10mA; V _{NO_} or V _{NC_} =1.5V	UM4717	Room		3.0	4.5	Ω
				Full			5	
			UM4717Q	Room		4.5	6	
				Full			7	
ΔR _{ON}	On Resistance Match Between Channels (Notes 4, 5)	V ₊ =+2.7V, I _{COM_} =10mA; V _{NO_} or V _{NC_} =1.5V	UM4717	Room		0.1	0.3	Ω
				Full			0.4	
			UM4717Q	Room		0.5	0.6	
				Full			0.9	
R _{FLAT}	On Resistance Flatness (Note 6)	V ₊ =+2.7V, I _{COM_} =10mA; V _{NO_} or V _{NC_} = 1.0V, 1.5V, 2.0V	UM4717	Room		0.6	1.2	Ω
				Full			1.5	
			UM4717Q	Room		1.5	1.8	
				Full			2.0	

Note 2: The parts are 100% tested at $+25^\circ C$ only, and guaranteed by design over the specified temperature range.

Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.

Note 4: Guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Between any two switches.

Electrical Characteristics (Single +3V Supply) (Continued)

($V_+ = +2.7V$ to $+3.6V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +3.0V$, $T_A = +25^\circ C$) (Notes 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (-40 °C to 85 °C)			Unit
				Min	Typ	Max	
AC Electrical Characteristics							
t _{ON}	Turn-On Time	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 1; V _{IH} =1.5V, V _{IL} =0V	Room Full		40	80 100	ns
t _{OFF}	Turn-Off Time	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 1; V _{IH} =1.5V, V _{IL} =0V	Room Full		20	40 50	ns
t _{BBM}	Break Before Make Time (Note 4)	V _{NO_} , V _{NC_} =1.5V; R _L =300Ω, C _L =35pF, Figure 2	Room Full	1	8		ns
t _{SKEW}	Skew (Note 4)	R _S =39Ω, C _L =50pF, Figure 3	Full		0.15	2	ns
Q _{INJ}	Charge Injection	C _L =1.0nF, Figure 4 V _{GEN} =1.5V, R _{GEN} =0Ω	Room		5		pC
V _{ISO}	Off Isolation	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-50		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-70		
V _{CT}	Crosstalk (Note 7)	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-70		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-90		
BW	-3dB Bandwidth	Signal=0dBm, R _L =50Ω, C _L =5pF, Figure 5	Room		300		MHz
THD	Total Harmonic Distortion	R _L =600Ω, V _{COM_} =2V _{P-P}	Room		0.03		%
Capacitance							
C _{NO_(OFF)} C _{NC_(OFF)}	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room		15		pF

Note 2: The parts are 100% tested at $+25^\circ C$ only, and guaranteed by design over the specified temperature range.

Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.

Note 4: Guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Between any two switches.

Electrical Characteristics (Single +5V Supply)

($V_+ = +4.2V$ to $+5.5V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +5.0V$, $T_A = +25^\circ C$) (Notes 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (−40 °C to 85 °C)			Unit	
				Min	Typ	Max		
DC Electrical Characteristics								
V _{COM_} V _{NO_} V _{NC_}	Analog Signal Range		Full	0		V+	V	
V+	Power Supply Range		Full	1.8		5.5	V	
I+	Supply Current	V ₊ =+5.5V, V _{IN_} =0V or V+	Full			1	μA	
I _{COM_(ON)}	COM_On Leakage Current (Note 4)	V ₊ =+5.5V, V _{COM_} =1.0V, 4.5V; V _{NO_} or V _{NC_} =1.0V, 4.5V, or Floating	Room Full	-1 -2	+0.01	+1 +2	nA	
I _{OFF}	OFF State Leakage Current (Note 4)	V ₊ =+5.5V, V _{COM_} =1.0V, 4.5V; V _{NO_} or V _{NC_} =1.0V, 4.5V	Room Full	-0.5 -1	+0.01	+0.5 +1	nA	
V _{IH}	Input High Voltage		Full	2.3			V	
V _{IL}	Input Low Voltage		Full			0.8	V	
I _{IN}	Input Leakage Current	V ₊ =+5.5V, V _{IN_} =0 or V+	Full	-100		+100	nA	
R _{ON}	On-Resistance (Note 4)	V ₊ =+4.2V, I _{COM_} =10mA; V _{NO_} or V _{NC_} =3.5V	UM4717	Room		1.7	3	Ω
				Full			3.5	
			UM4717Q	Room		2.5	3.5	
				Full			4	
ΔR _{ON}	On Resistance Match Between Channels (Notes 4, 5)	V ₊ =+4.2V, I _{COM_} =10mA; V _{NO_} or V _{NC_} = 3.5V	UM4717	Room		0.1	0.3	Ω
				Full			0.4	
			UM4717Q	Room		0.5	0.6	
				Full			0.9	
R _{FLAT}	On Resistance Flatness (Note 6)	V ₊ =+4.2V, I _{COM_} =10mA; V _{NO_} or V _{NC_} =1.0V, 2.0V, 3.5V	UM4717	Room		0.4	1.2	Ω
				Full			1.5	
			UM4717Q	Room		0.9	1.2	
				Full			1.5	

Note 2: The parts are 100% tested at $+25^\circ C$ only, and guaranteed by design over the specified temperature range.

Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.

Note 4: Guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Between any two switches.

Electrical Characteristics (Single +5V Supply) (Continued)

($V_+ = +4.2V$ to $+5.5V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_+ = +5.0V$, $T_A = +25^\circ C$) (Notes 2, 3)

Symbol	Parameter	Test Conditions	Temp	Limits (−40 °C to 85 °C)			Unit
				Min	Typ	Max	
AC Electrical Characteristics							
t _{ON}	Turn-On Time	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 1;	Room Full		30	80 100	ns
t _{OFF}	Turn-Off Time	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 1;	Room Full		20	40 50	ns
t _{BBM}	Break Before Make Time (Note 4)	V _{NO_} , V _{NC_} =3.0V; R _L =300Ω, C _L =35pF, Figure 2	Room Full	1	8		ns
t _{SKEW}	Skew (Note 4)	R _S =39Ω, C _L =50pF, Figure 3	Full		0.15	2	ns
Q _{INJ}	Charge Injection	C _L =1.0nF, Figure 4 V _{GEN} =1.5V, R _{GEN} =0Ω	Room		9		pC
V _{ISO}	Off Isolation	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-50		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-70		
V _{CT}	Crosstalk (Note 7)	f=10MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5	Room		-70		dB
		f=1MHz; V _{NO_} , V _{NC_} =1V _{P-P} ; R _L =50Ω, C _L =5pF, Figure 5			-90		
BW	-3dB Bandwidth	Signal=0dBm, R _L =50Ω, C _L =5pF, Figure 5	Room		300		MHz
THD	Total Harmonic Distortion	R _L =600Ω, V _{COM_} =2V _{P-P}	Room		0.03		%
Capacitance							
C _{NO_(OFF)} C _{NC_(OFF)}	NO_, NC_ Off Capacitance	f=1MHz, Figure 6	Room		9		pF
C _(ON)	Switch On Capacitance	f=1MHz, Figure 6	Room		15		pF

Note 2: The parts are 100% tested at $+25^\circ C$ only, and guaranteed by design over the specified temperature range.

Note 3: The algebraic convention used in this data sheet is where the most negative value is a minimum and the most positive value is a maximum.

Note 4: Guaranteed by design.

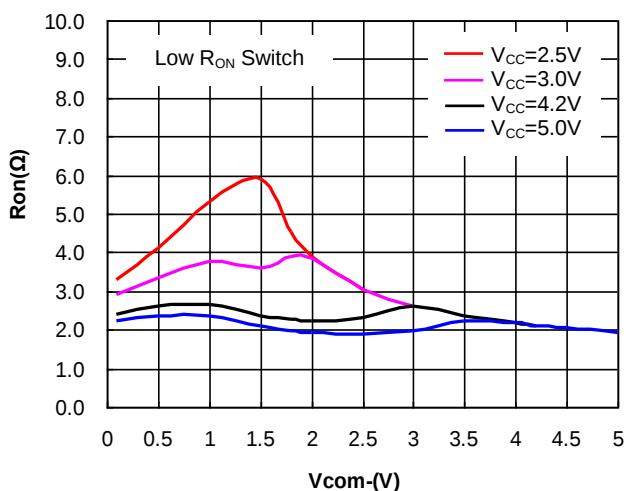
Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

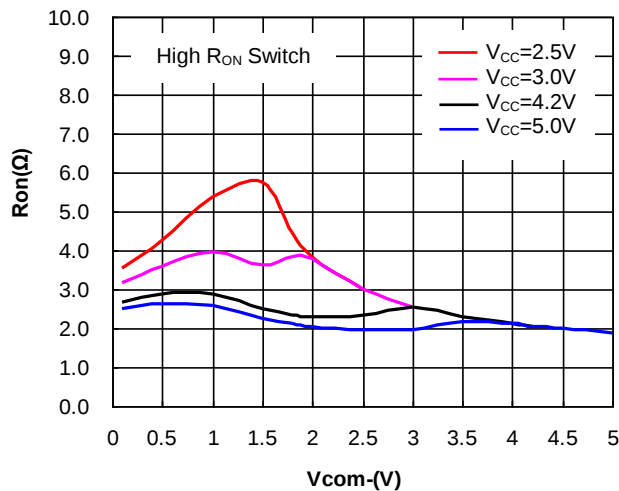
Note 7: Between any two switches.

Typical Operating Characteristics

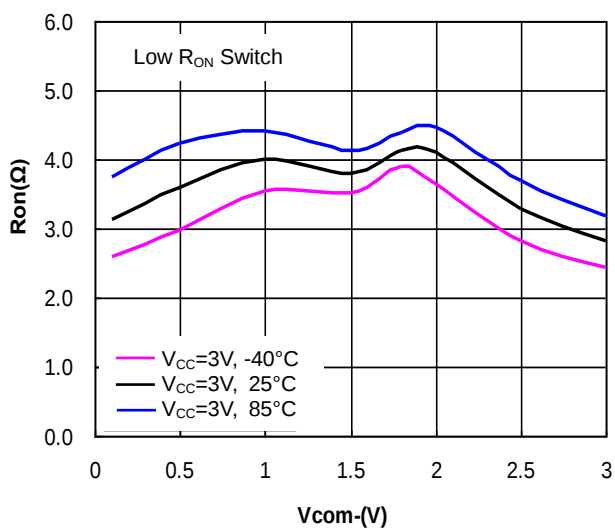
On Resistance vs. COM_Voltage



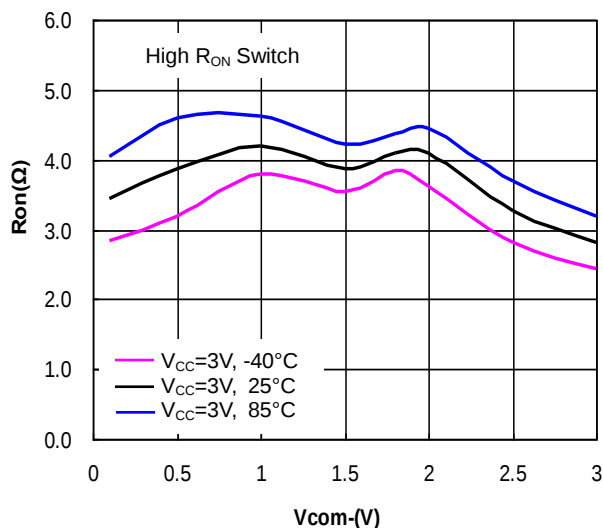
On Resistance vs. COM_Voltage



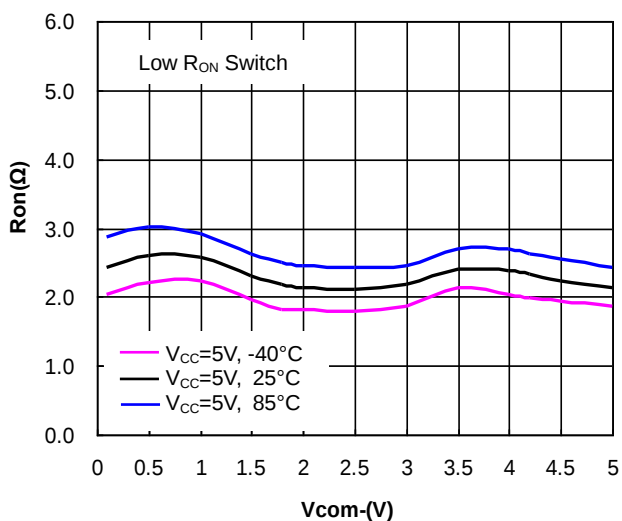
On Resistance vs. COM_Voltage



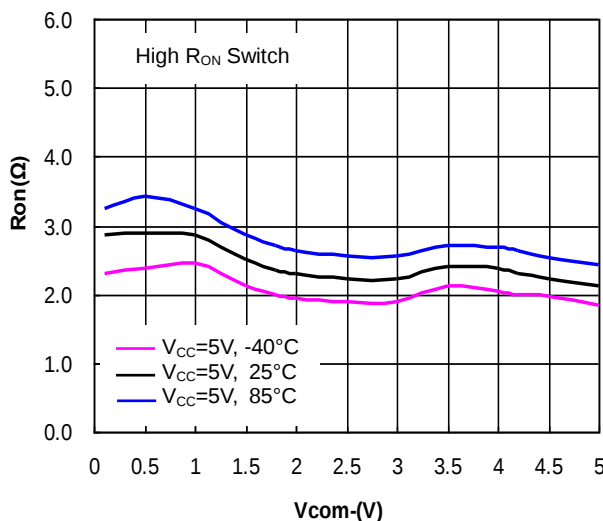
On Resistance vs. COM_Voltage



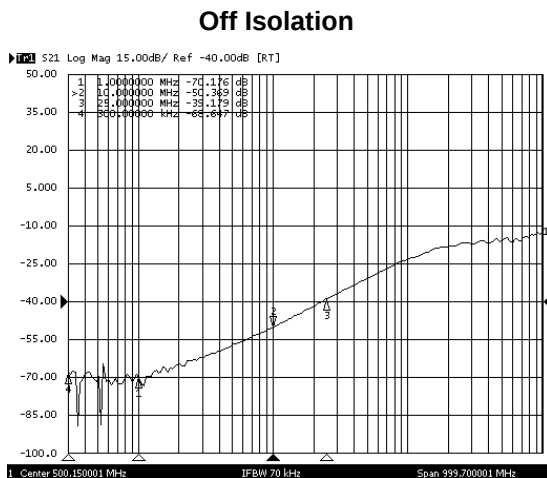
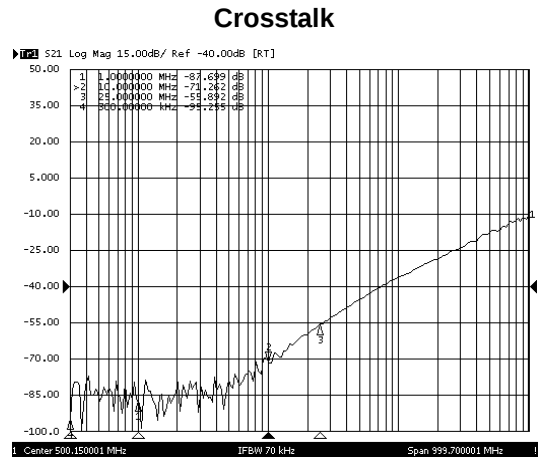
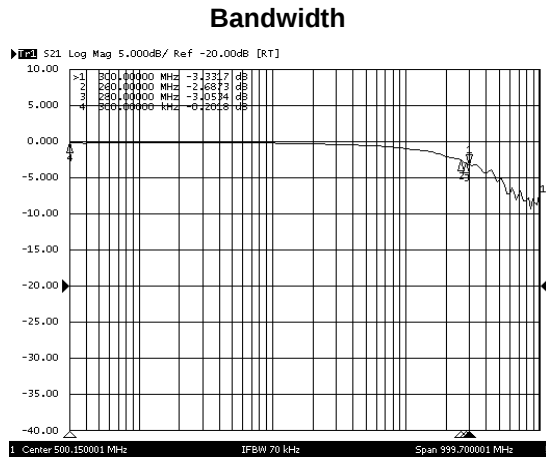
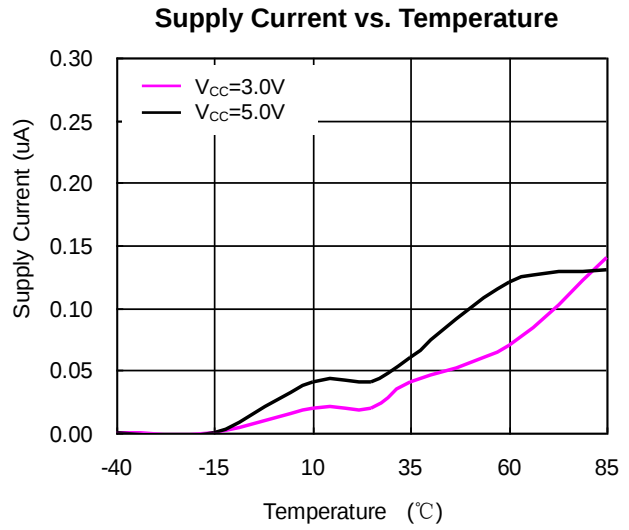
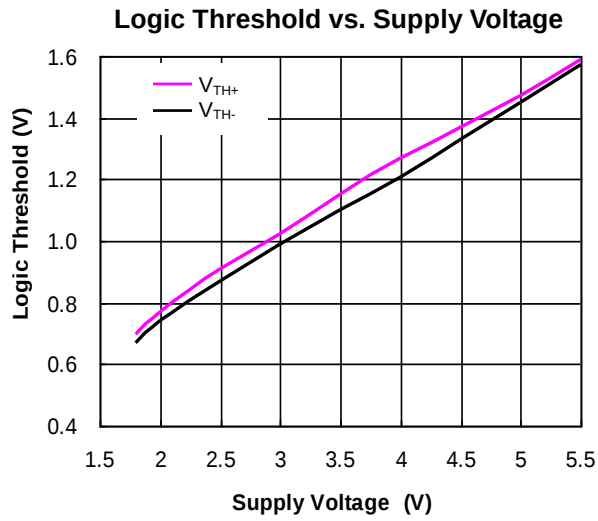
On Resistance vs. COM_Voltage



On Resistance vs. COM_Voltage



Typical Operating Characteristics (Continued)



Detailed Description

The UM4717/UM4717Q high-speed, low-voltage, low on-resistance (R_{ON}), dual SPDT analog switch operates from a single +1.8V to +5.5V supply. The switch features break-before-make switching operation and fast switching speeds ($t_{ON}=80\text{ns}$ (max), $t_{OFF}=40\text{ns}$ (max)).

The switch has low 15pF on-channel capacitance, which allows for 12Mbps switching of the data signals for USB 1.0/1.1 applications. The UM4717/UM4717Q is designed to switch D+ and D- USB signals with a guaranteed skew of less than 2ns (see Figure 4) as measured from 50% of the input signal to 50% of the output signal.

Applications Information

Digital Control Inputs

The UM4717/UM4717Q logic inputs accept up to +5.5V regardless of supply voltage. For example, with a +3.3V supply, IN₋ can be driven low to GND and high to +5.5V allowing for mixing of logic levels in a system. Driving the control logic inputs rail-to-rail minimizes power consumption. For a +3V supply voltage, the logic thresholds are 0.5V (low) and 1.4V (high); for a +5V supply voltage, the logic thresholds are 0.8V (low) and 2.0V (high).

Analog Signal Levels

The on-resistance of the UM4717/UM4717Q changes very little for analog input signals across the entire supply voltage range (see the Typical Operating Characteristics). The switches are bidirectional, so the NO₋, NC₋, and COM₋ pins can be either inputs or outputs.

Power-Supply Sequencing and Over-Voltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V_+ before applying analog signals, especially if the analog signal is not current-limited.

Test Circuits

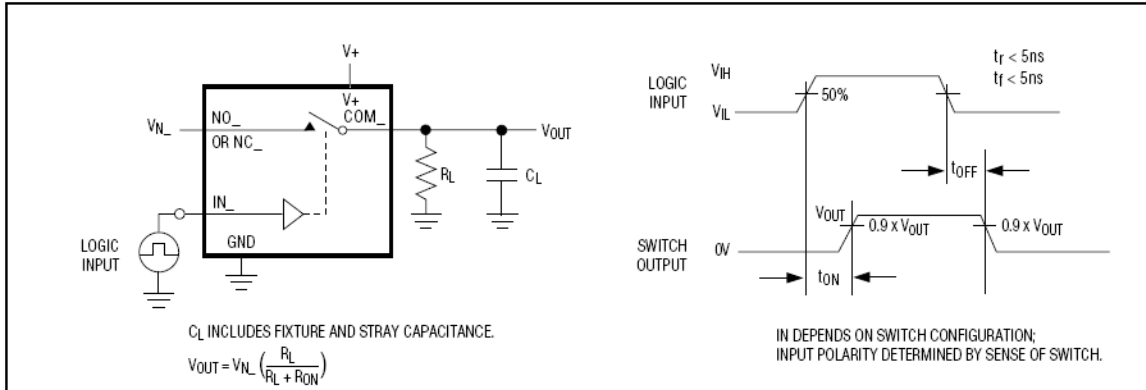


Figure 1. Switching Time

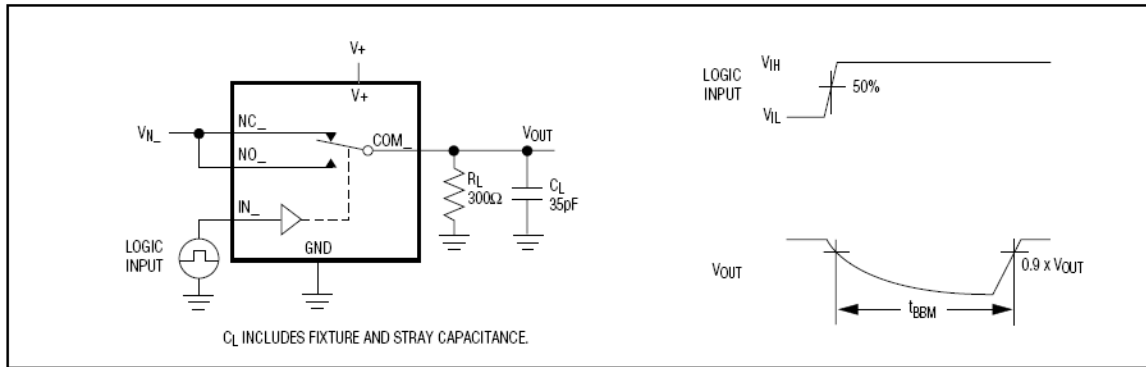


Figure 2. Break-Before-Make Interval

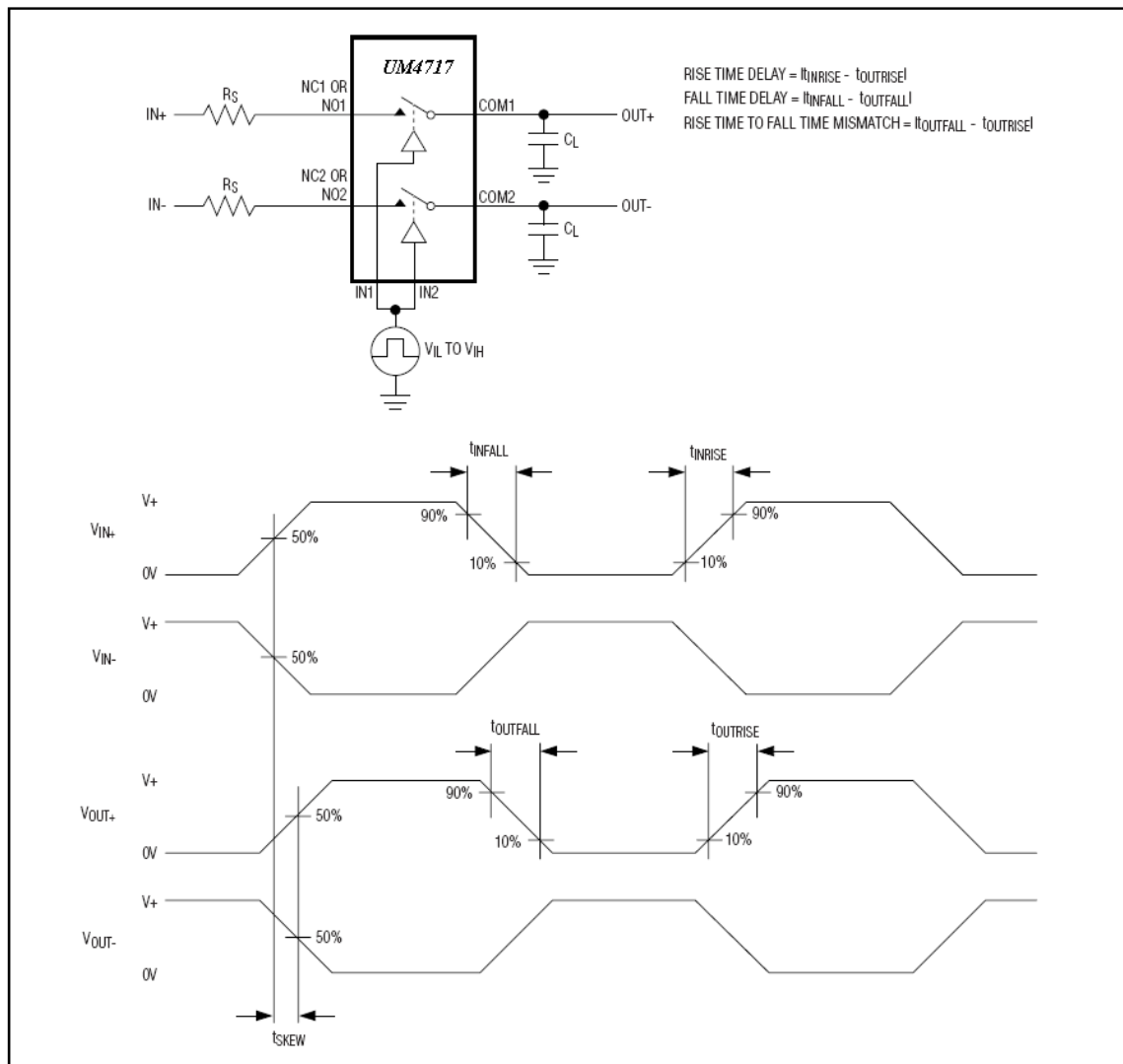


Figure 3. Output Signal Skew

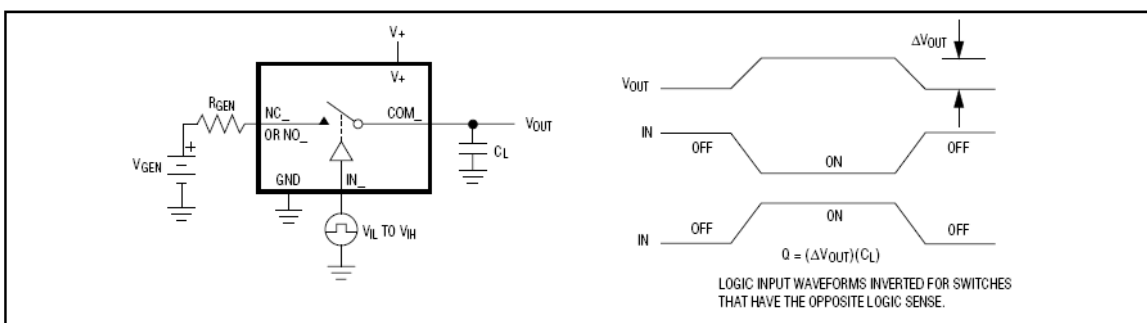


Figure 4. Charge Injection

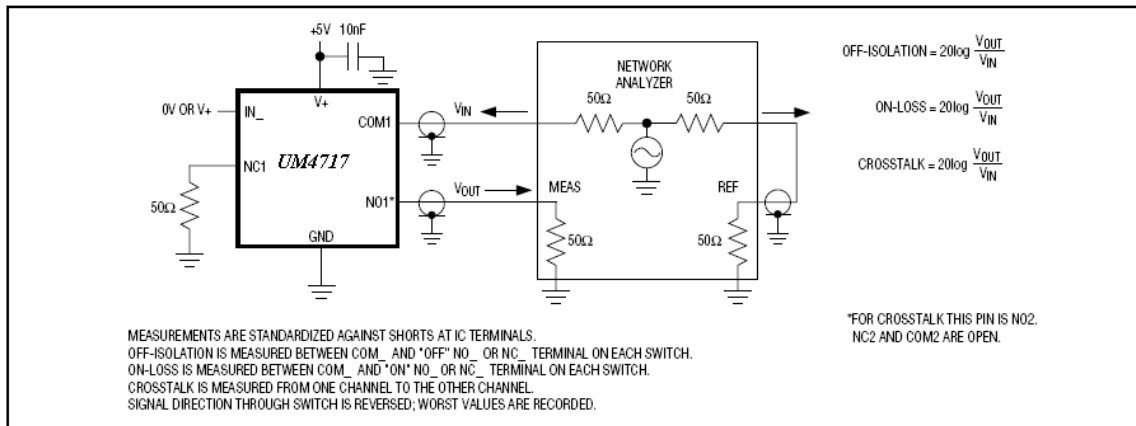


Figure 5. On-Loss, Off-Isolation, and Crosstalk

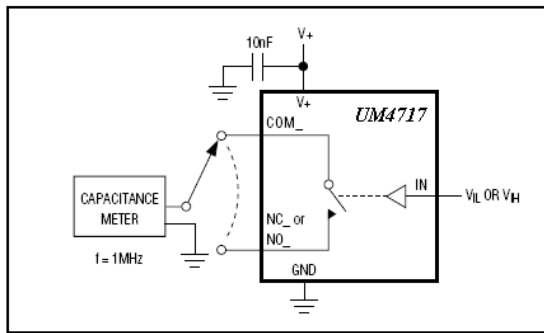


Figure 6. Channel Off/On-Capacitance

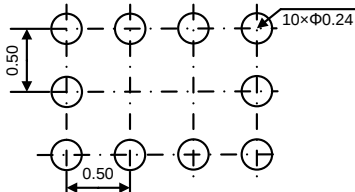
Package Information

CSP10 1.90×1.40

Outline Drawing

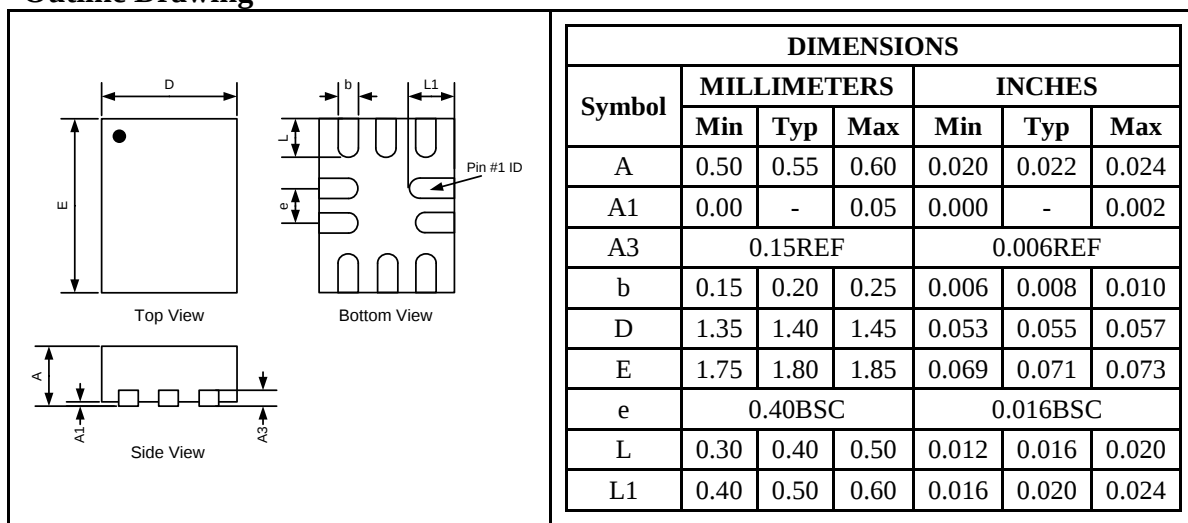
DIMENSIONS						
Symbol	MILLIMETERS			INCHES		
	Min	Typ	Max	Min	Typ	Max
A	-	-	0.68	-	-	0.027
A1	0.21	0.231	0.24	0.0083	0.0091	0.0094
A2	0.40	0.41	0.42	0.015	0.016	0.017
b	0.27	0.30	0.32	0.011	0.012	0.013
D	1.82	-	1.90	0.072	-	0.075
E	1.32	-	1.40	0.052	-	0.055
e	0.50TYP			0.020TYP		

Land Pattern

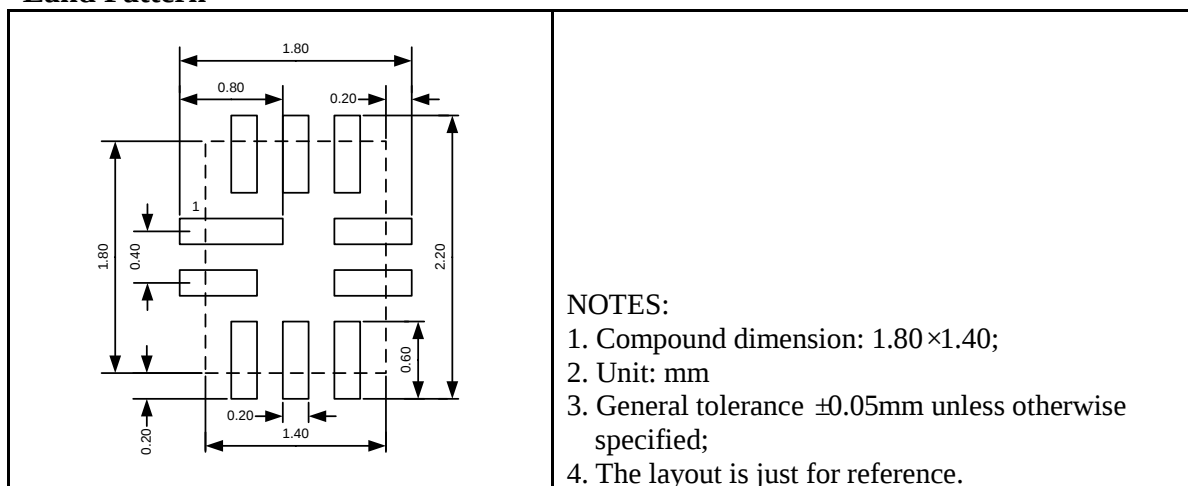
	NOTES: 1. Bump is Lead Free Sn/Ag/Cu. 2. Unit: mm. 3. Non-solder mask defined copper landing pad. 4. Laser Mark on silicon die back; back-lapped.
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QFN10 1.80 × 1.40

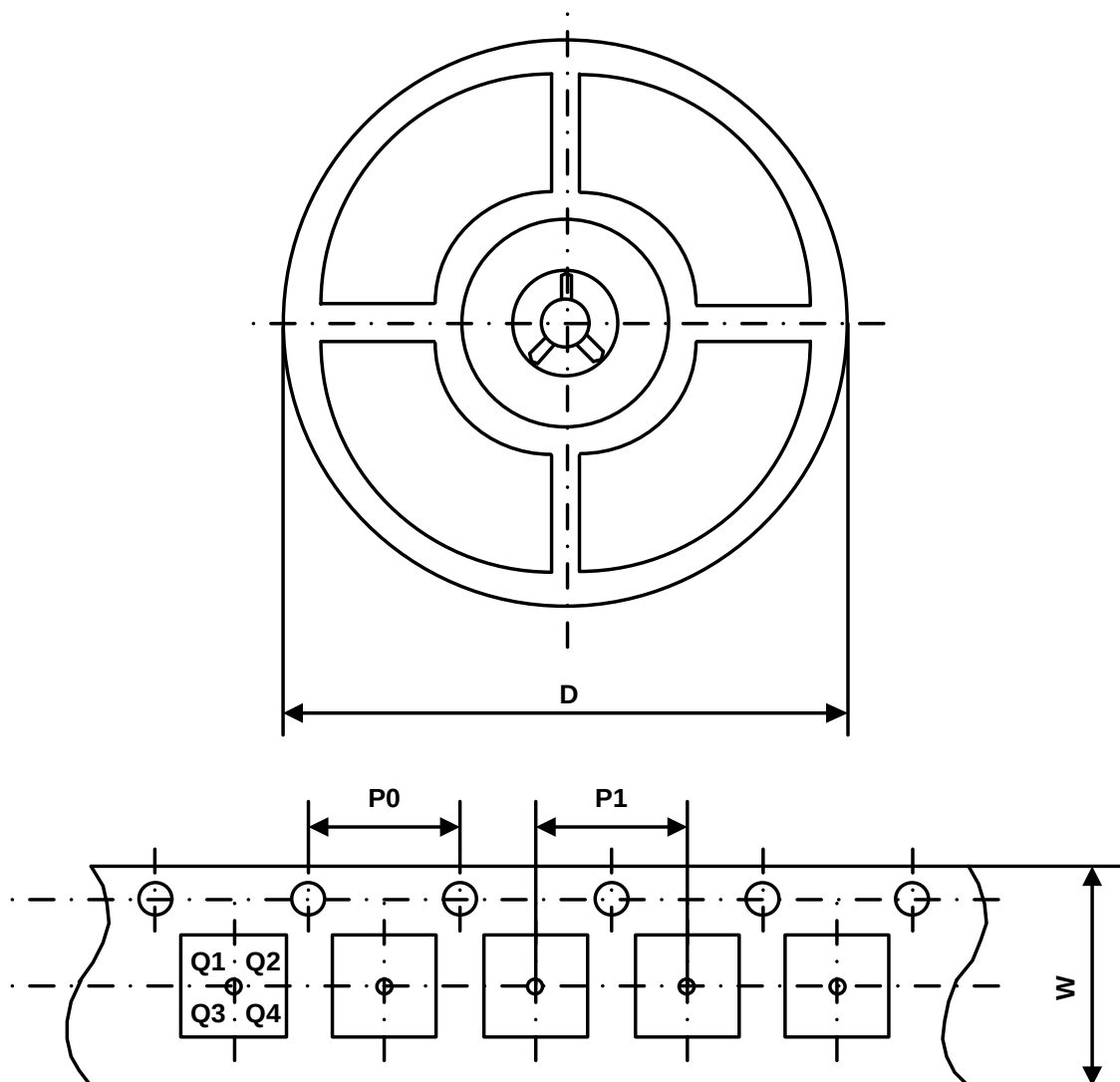
Outline Drawing



Land Pattern



Packing Information



Part Number	Package Type	Carrier Width (W)	Pitch (P0)	Pitch (P1)	Reel Size (D)	PIN 1 Quadrant
UM4717	CSP10 1.90×1.40	8 mm	4 mm	4 mm	180 mm	Q2
UM4717Q	QFN10 1.80×1.40	8 mm	4 mm	4 mm	180 mm	Q1

GREEN COMPLIANCE

Union Semiconductor is committed to environmental excellence in all aspects of its operations including meeting or exceeding regulatory requirements with respect to the use of hazardous substances. Numerous successful programs have been implemented to reduce the use of hazardous substances and/or emissions.

All Union components are compliant with the RoHS directive, which helps to support customers in their compliance with environmental directives. For more green compliance information, please visit:

http://www.union-ic.com/index.aspx?cat_code=RoHSDeclaration

IMPORTANT NOTICE

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